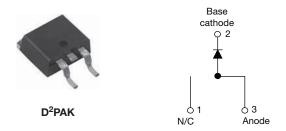


VS-MBRB1635PbF, VS-MBRB1645PbF

Vishay Semiconductors

High Performance Schottky Rectifier, 16 A

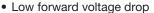


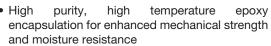
| PRODUCT SUMMARY | | | | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|--|--|--|
| Package | TO-263AB (D ² PAK) | | | | | | | |
| I _{F(AV)} | 16 A | | | | | | | |
| V_{R} | 35 V, 45 V | | | | | | | |
| V _F at I _F | 0.63 | | | | | | | |
| I _{RM} | 40 mA at 125 °C | | | | | | | |
| T_J max. | 150 °C | | | | | | | |
| Diode variation | Single die | | | | | | | |
| E _{AS} | 24 mJ | | | | | | | |

FEATURES











HALOGEN

FREE

 Guard ring for enhanced ruggedness and long term reliability

- term reliabilityMeets MSL level 1, per J-STD-020, LF maximum peak of
- Meets MSL level 1, per J-S1D-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|-----------------------------------|--|-------------|-------|--|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | | |
| I _{F(AV)} | Rectangular waveform | 16 | А | | | | | | |
| V _{RRM} | | 35/45 | V | | | | | | |
| I _{FSM} | t _p = 5 μs sine | 1800 | Α | | | | | | |
| V _F | 16 A _{pk} , T _J = 125 °C | 0.57 | V | | | | | | |
| TJ | | -65 to +150 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | |
|--|------------------|----|----|----|--|--|--|
| PARAMETER SYMBOL VS-MBRB1635PbF VS-MBRB1645PbF UNITS | | | | | | | |
| Maximum DC reverse voltage | V_R | 35 | 45 | \/ | | | |
| Maximum working peak reverse voltage | V _{RWM} | 35 | 45 | V | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|-----------------------------------|--------------------|---|--|--------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | | | |
| Maximum average forward current | I _{F(AV)} | T _C = 134 °C, rated V _R | T _C = 134 °C, rated V _R | | | | | |
| Non-repetitive peak surge current | I _{FSM} | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated V _{RRM} applied | | А | | | |
| | | Surge applied at rated load condition half wave single phase 60 Hz | | 150 | | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH | | 24 | mJ | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 3.6 | Α | | | |



VS-MBRB1635PbF, VS-MBRB1645PbF

Vishay Semiconductors

| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|--------------------------------|--------------------------------|---|-------------------------|-------|------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | | | |
| Maximum farward valtage drap | V _{FM} ⁽¹⁾ | 16 A | T _J = 25 °C | 0.63 | V | | | |
| Maximum forward voltage drop | VFM ('') | 10 A | T _J = 125 °C | 0.57 | | | | |
| Maximum instantaneous | I _{RM} ⁽¹⁾ | T _J = 25 °C | Rated DC voltage | 0.2 | mA | | | |
| reverse current | IRM (*/ | T _J = 125 °C | hated DC voltage | 40 | IIIA | | | |
| Maximum junction capacitance | C _T | V _R = 5 V _{DC} (test signal ran | 1400 | pF | | | | |
| Typical series inductance | L _S | Measured lead from top o | 8.0 | nΗ | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|---------|-------------------|--------------------------------------|-------------|------------------|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction temperature | range | TJ | | -65 to +150 | °C | | |
| Maximum storage temperature | range | T _{Stg} | | -65 to +175 | C | | |
| Maximum thermal resistance, junction to case | | R_{thJC} | DC operation | 1.50 | °C/W | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | | | |
| Approximate weight | | | | 2 | g | | |
| | | | | 0.07 | OZ. | | |
| Mounting torque | minimum | | | 6 (5) | kgf · cm | | |
| Mounting torque - | maximum | | | 12 (10) | (lbf \cdot in) | | |
| Marking device | | | Case style D ² PAK | MBRE | 31635 | | |

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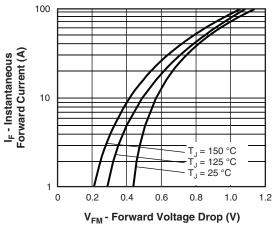


Fig. 1 - Maximum Forward Voltage Drop Characteristics

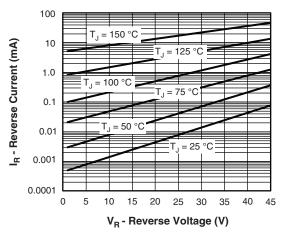


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

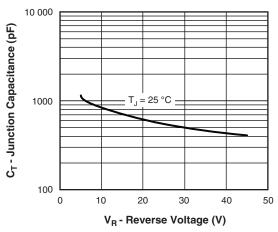


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

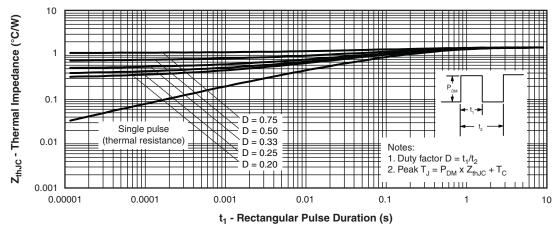


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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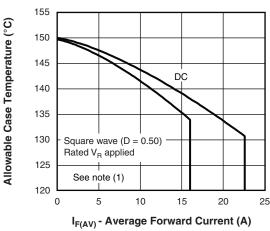


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

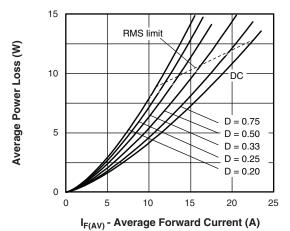


Fig. 6 - Forward Power Loss Characteristics

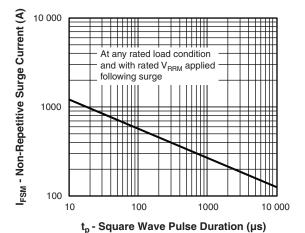


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

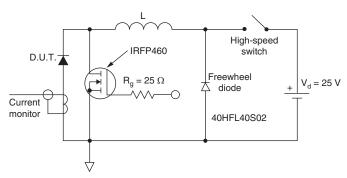


Fig. 8 - Unclamped Inductive Test Circuit

Note

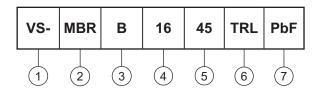
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \text{ applied} \\ \end{array}$

VS-MBRB1635PbF, VS-MBRB1645PbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Essential part number

B = surface mount

Current rating (16 = 16 A)

5 - Voltage code = V_{RRM} 35 = 35 V 45 = 45 V

6 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

7 - PbF = lead (Pb)-free

| ORDERING INFORMATION | | | | | | | | | | |
|----------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | | |
| VS-MBRB1635PbF | 50 | 1000 | Antistatic plastic tubes | | | | | | | |
| VS-MBRB1635TRRPbF | 800 | 800 | 13" diameter reel | | | | | | | |
| VS-MBRB1635TRLPbF | 800 | 800 | 13" diameter reel | | | | | | | |
| VS-MBRB1645PbF | 50 | 1000 | Antistatic plastic tubes | | | | | | | |
| VS-MBRB1645TRRPbF | 800 | 800 | 13" diameter reel | | | | | | | |
| VS-MBRB1645TRLPbF | 800 | 800 | 13" diameter reel | | | | | | | |

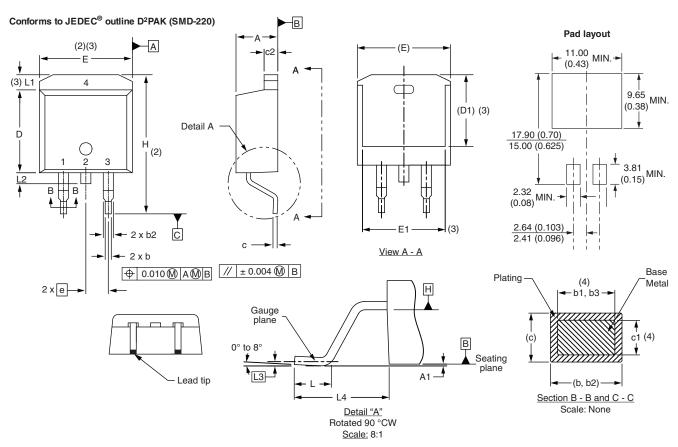
| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?95046 | | | | | |
| Part marking information | www.vishay.com/doc?95054 | | | | | |
| Packaging information | www.vishay.com/doc?95032 | | | | | |
| SPICE model | www.vishay.com/doc?95407 | | | | | |



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | ERS INCHES | | NOTES | SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|---------|-------------|-------|------------|-------|-------|---------|--------|-------|-------|-------|-------|
| STWIBOL | MIN. | MAX. | MIN. | MAX. | NOTES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | L3 | 0.25 | BSC | 0.010 |) BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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Vishay

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